

COMMUNICATION

[View Article Online](#)
[View Journal](#) | [View Issue](#)Cite this: *Nanoscale Adv.*, 2022, 4, 3318Received 14th June 2022
Accepted 2nd July 2022

DOI: 10.1039/d2na00373b

rsc.li/nanoscale-advancesSynthesis of textured discontinuous-nanoisland $\text{Ca}_3\text{Co}_4\text{O}_9$ thin films†Binbin Xin,^{ID}* Arnaud Le Febvrier,^{ID} Jun Lu, Biplab Paul^{ID}‡ and Per Eklund^{ID}*

Controllable engineering of the nanoporosity in layered $\text{Ca}_3\text{Co}_4\text{O}_9$ remains a challenge. Here, we show the synthesis of discontinuous films with islands of highly textured $\text{Ca}_3\text{Co}_4\text{O}_9$, effectively constituting distributed nanoparticles with controlled porosity and morphology. These discontinuously dispersed textured $\text{Ca}_3\text{Co}_4\text{O}_9$ nanoparticles may be a candidate for hybrid thermoelectrics.

The misfit-layered calcium cobaltate $\text{Ca}_3\text{Co}_4\text{O}_9$ has a complex crystal structure composed of CoO_2 conductive layers and oxygen deficient rock-salt type Ca_2CoO_3 insulating layers.¹ $\text{Ca}_3\text{Co}_4\text{O}_9$ can be used in various energy-harvesting systems because of its high thermal stability and oxidation resistance. This material is an attractive p-type thermoelectric material with a high Seebeck coefficient S , moderate electrical conductivity σ and low thermal conductivity. It also can be used as an active material in Li-ion-battery anodes,^{2,3} hydrogen evolution and oxygen reduction reactions^{4,5} and supercapacitors with high cycling stability.^{6,7}

Nanostructures such as nanoparticles⁸ and nanoporous films^{9,10} are common means to alter electrical, catalytic, and thermal properties of inorganic materials. In previous work, we have shown that nanoporous $\text{Ca}_3\text{Co}_4\text{O}_9$ films on sapphire exhibit a thermal conductivity of $0.82 \text{ W m}^{-1} \text{ K}^{-1}$, which is nearly twofold lower than that obtained from comparable nonporous $\text{Ca}_3\text{Co}_4\text{O}_9$ films.¹¹ Furthermore, nanoporous $\text{Ca}_3\text{Co}_4\text{O}_9$ films grown on mica can be obtained by reactions in hydrated CaO/CoO multilayers.¹² The volume shrinkage in $\text{Ca(OH)}_2/\text{Co}_3\text{O}_4$ multilayers and the out-of-plane orientation relationship between Ca(OH)_2 and Co_3O_4 induce the formation of faceted and oriented nanopores in textured $\text{Ca}_3\text{Co}_4\text{O}_9$ films.

Here, we show control of morphology and porosity in textured $\text{Ca}_3\text{Co}_4\text{O}_9$ films, to form discontinuous films with islands of highly textured $\text{Ca}_3\text{Co}_4\text{O}_9$, effectively constituting distributed nanoparticles. The discontinuous films with islands of highly textured $\text{Ca}_3\text{Co}_4\text{O}_9$ were synthesized by radio-frequency (rf) sputtering followed by post-deposition annealing without any templates. Such films of discontinuously dispersed $\text{Ca}_3\text{Co}_4\text{O}_9$ nanoparticles may be a promising filler in polymer matrixes for hybrid and composite materials in, *e.g.*, thermoelectrics.^{13–16}

The $\text{Ca}_3\text{Co}_4\text{O}_9$ nanoparticles were obtained by a similar method to that published in our earlier work.¹² First, the $\text{CaO/Co}_3\text{O}_4$ multilayer films were deposited on muscovite mica (001) and sapphire substrates (001) at 600°C by reactive radio-frequency magnetron sputtering. The multilayers consisted of eight alternative bilayers of CaO (top layer) and Co_3O_4 . The overall $\text{Ca} : \text{Co}$ elemental ratio in the multilayer films was varied and set to 1 : 1.38 (close to stoichiometric $\text{Ca}_3\text{Co}_4\text{O}_9$), 1 : 0.82, 1 : 0.67, and 1 : 0.52 by varying CaO and Co_3O_4 deposition times of their respective layer. Then, all the as-deposited multilayer films were exposed to a humid environment (0.88 relative humidity at constant temperature) to form $\text{Ca(OH)}_2/\text{Co}_3\text{O}_4$ multilayer films at room temperature for two days, as described earlier.^{12,17} At the final stage, the different $\text{Ca(OH)}_2/\text{Co}_3\text{O}_4$ multilayer films were annealed at 700°C in air for 2 h.

X-ray diffraction (XRD) measurements were performed using an X'Pert PRO MRD diffractometer from PANalytical using $\text{Cu K}_{\alpha 1,2}$ radiation with a nickel filter in the Bragg–Brentano configuration (θ – 2θ scans). The surface morphology of the films was studied by scanning electron microscopy (SEM) using a LEO Gemini 1550 Zeiss with a 10 kV operating voltage. Transmission electron microscopy (TEM) was carried out on an FEI Tecnai G2 TF20 UT instrument operated at 200 kV. The Ca/Co elemental ratio was determined using energy-dispersive X-ray spectroscopy (EDS) by measuring at several positions on each sample growing on sapphire. The surface porosity fraction or coverage was determined from the SEM micrographs analysed using the software ImageJ (Java version).¹⁸ The electrical conductivity σ

Thin Film Physics Division, Department of Physics, Chemistry and Biology (IFM), Linköping University, SE-58183 Linköping, Sweden. E-mail: binbin.xin@liu.se; per.eklund@liu.se

† Electronic supplementary information (ESI) available. See <https://doi.org/10.1039/d2na00373b>

‡ Present address: Platit AG, Selzach, Switzerland.

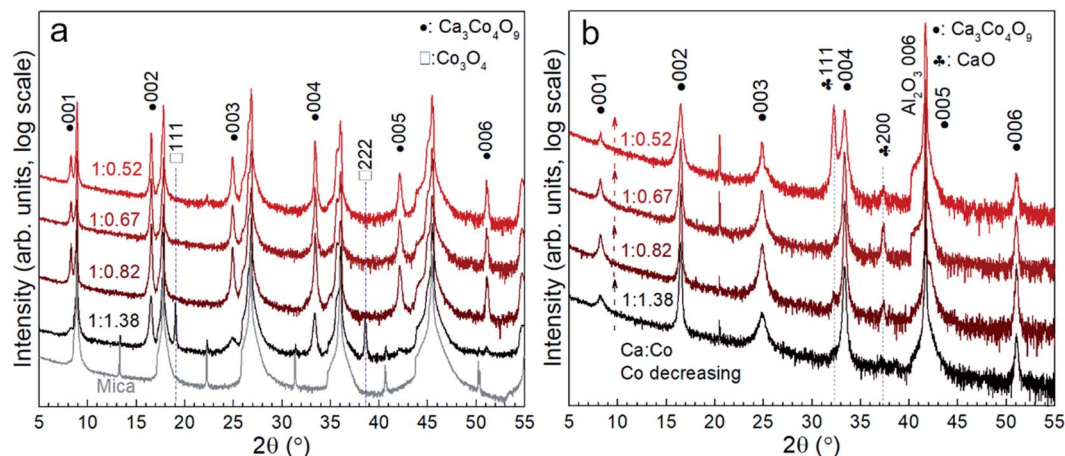


Fig. 1 X-ray diffractograms of the annealed films grown on mica (a) and sapphire (b) with decreasing Co content in the films with Ca/Co ratios: 1 : 1.38, 1 : 0.82, 1 : 0.67, and 1 : 0.52, respectively.

was calculated from the sheet resistance measured by using a four-point probe Jandel RM3000 station, and the film thickness was determined from the cross-sectional SEM images. The Seebeck coefficient was determined from the slope of the temperature gradient-voltage characteristics measured using a homemade Seebeck measurement setup system described elsewhere.^{12,17}

Fig. 1 shows the X-ray diffraction patterns of the Ca₃Co₄O₉ films on mica and sapphire as a function of the Ca/Co ratio: 1 : 1.38, 1 : 0.82, 1 : 0.67, and 1 : 0.52, respectively. The Ca/Co elemental ratios were measured from the different annealed films grown on sapphire by EDS and were the same as those in the as-deposited multilayer films grown on sapphire and mica and the annealed films on mica, respectively. Diffraction peaks for 001, 002, 003, 004, 005, and 006 reflections from Ca₃Co₄O₉ and 111 and 222 reflections from Co₃O₄ can be observed in the film on mica with the initial composition (1 : 1.38, the closest to

the stoichiometric Ca₃Co₄O₉) in Fig. 1a. With decreasing Co content (Ca : Co 1 : 0.82 → 1 : 0.52), pure-phase Ca₃Co₄O₉ can be identified in the films on mica from the XRD patterns (Fig. 1a). The intensity of peaks of Ca₃Co₄O₉ growing on mica remains approximately the same in Fig. 1a. As known and observed from our earlier work,^{19–21} the excess Ca migrates and is incorporated in an amorphous layer between the nanoporous Ca₃Co₄O₉ films and the mica substrate and will be discussed below. However, the pure-phase Ca₃Co₄O₉ can be seen from the film growing on sapphire with Ca : Co = 1 : 1.38 (Fig. 1b). With increasing Ca content, additional CaO can be observed for the films on sapphire (Fig. 1b). This result indicates that some CaO remained in the annealed films on sapphire.

The SEM images of the morphology of Ca₃Co₄O₉ films on mica are shown in Fig. 2. The film on mica with the initial composition (1 : 1.38) shows morphology with few nanopores (Fig. 2a and e). With decreasing Co content, the morphology of

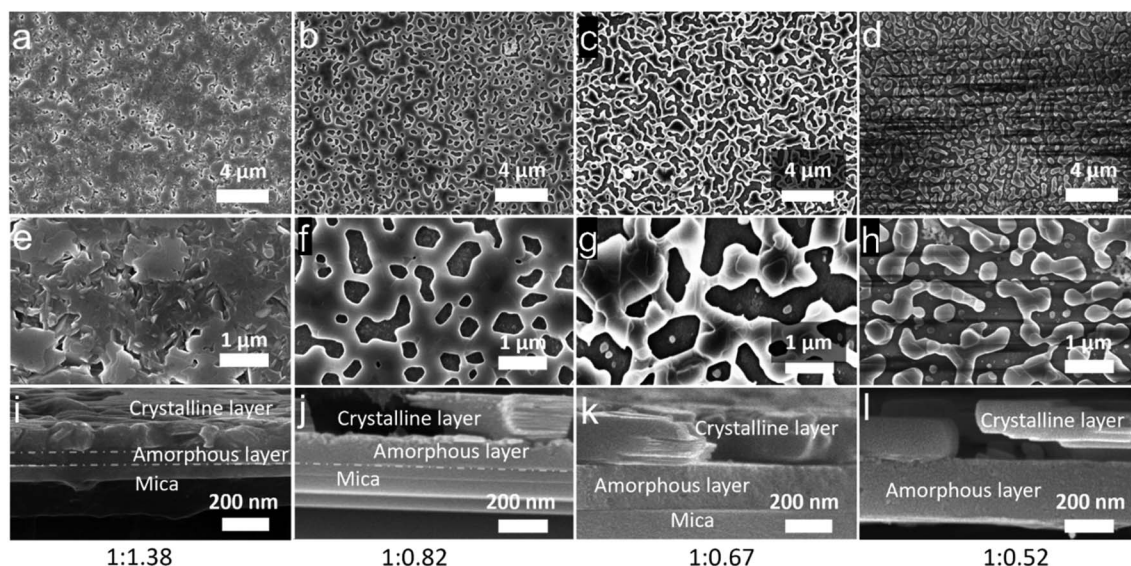


Fig. 2 SEM images and cross-sectional SEM images for the annealed films grown on mica with the different ratios of Ca/Co: (a, e and i) 1 : 1.38; (b, f and j) 1 : 0.82; (c, g and k) 1 : 0.67; (d, h and l) 1 : 0.52.



Table 1 The amorphous layer apparent thickness, $\text{Ca}_3\text{Co}_4\text{O}_9$ layer apparent thickness, and the apparent porosity fraction calculated from Fig. 2 as a function of the Ca : Co ratio in the films

Ca : Co elemental ratio	1 : 1.38	1 : 0.82	1 : 0.67	1 : 0.52
Thickness of the amorphous layer (nm)	81 ± 5	128 ± 6	179 ± 9	250 ± 12
Thickness of $\text{Ca}_3\text{Co}_4\text{O}_9$ (nm)	121 ± 7	178 ± 9	194 ± 10	170 ± 9
Porosity (%)	1.2 ± 0.1	22 ± 1	37 ± 1.9	46 ± 2.3

$\text{Ca}_3\text{Co}_4\text{O}_9$ in the annealed films change from a nanoporous continuous film morphology (Fig. 2b and f), *via* larger pores (Fig. 2c and g), to a discontinuous film of textured islands (Fig. 2d and h). The surface porosity fraction increases from 1.2% and 22% to 37% for the first three films (Table 1). For the discontinuous films, the corresponding value obtained from image analysis is an apparent “porosity” of 46% (Table 1), *i.e.* a surface coverage of 54%. This morphology is fundamentally different from the nanoporous films, though, in that the film is discontinuous and cannot be described as a porous film. The size of the nanoislands is mainly distributed from 50 nm to 1000 nm, as shown in Fig. S1.†

The electrical conductivity and the Seebeck coefficient of the $\text{Ca}_3\text{Co}_4\text{O}_9/\text{Co}_3\text{O}_4$ film are 27 S cm^{-1} and $139 \mu\text{V K}^{-1}$, respectively. The electrical conductivity of the nanoporous pure $\text{Ca}_3\text{Co}_4\text{O}_9$ film decreases from 112 to 38 S cm^{-1} with increasing the porosity from 22% up to 37%. The Seebeck coefficient of the nanoporous $\text{Ca}_3\text{Co}_4\text{O}_9$ films with different porosities is approximately $127 \mu\text{V K}^{-1}$, essentially the same for both. The Seebeck coefficient and electrical conductivity of the discontinuous film of textured $\text{Ca}_3\text{Co}_4\text{O}_9$ islands cannot be measured by using these setups since there is no continuous conduction path.

The cross-sectional SEM micrographs (Fig. 2i–l) reveal that the films are composed of a crystalline layer on top of an amorphous layer. As is known from our earlier work,^{20,21} this amorphous layer forms due to a reaction between the mica substrate and the initial films during annealing. The amorphous layer contains O, Al, and Si elements from mica and Ca element from the initial films. The film growing on mica with the initial composition (1 : 1.38) shows a crystalline layer with a thickness of 121 nm and an amorphous layer with a thickness of 81 nm (Fig. 2i). This indicates that the formation of $\text{Ca}_3\text{Co}_4\text{O}_9$ and amorphous layers occurs at same time during annealing. With increasing Ca content in the initial films, the pure crystalline $\text{Ca}_3\text{Co}_4\text{O}_9$ layer of the last three films shows a similar apparent thickness of around 170 nm for all the films, but the thickness of the amorphous layer increases from 130 nm to 240 nm (Fig. 2j–l and Table 1).

The SEM images of the morphology of $\text{Ca}_3\text{Co}_4\text{O}_9$ films on sapphire are shown in Fig. 3a–d. A dense film can be observed in the annealed film with Ca : Co = 1 : 1.38 (Fig. 3a). The nanoporous morphology with a nanopore size of ~ 200 nm can be observed in the annealed film with low Ca : Co = 1 : 0.82 (Fig. 3b). Upon further decreasing the Co content, the surface morphology seems to be composed of a mixture of two families

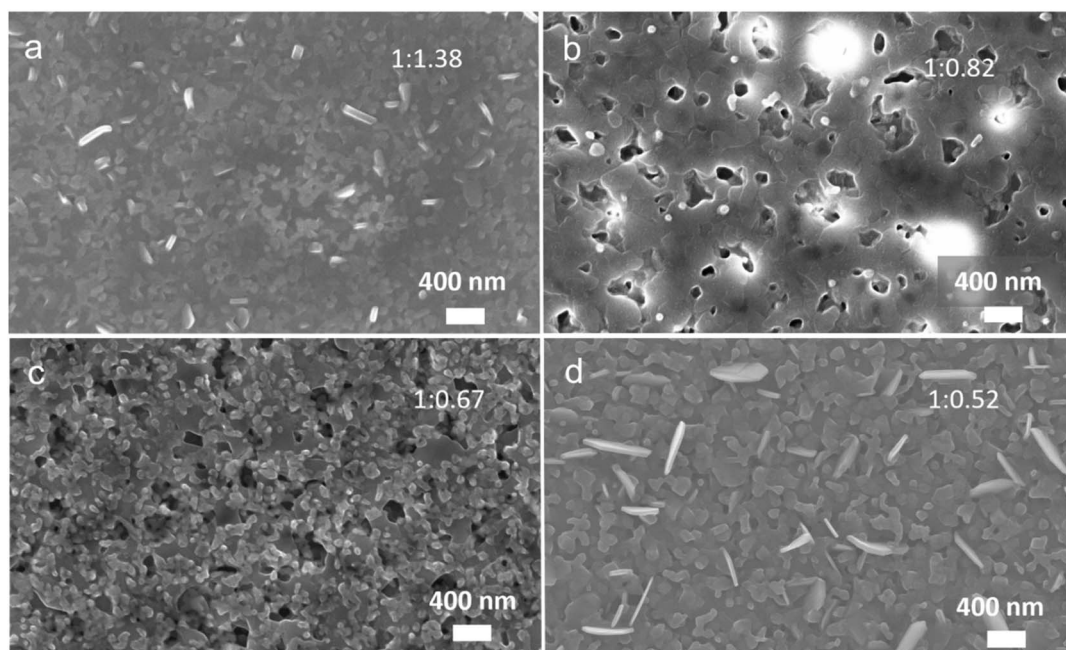


Fig. 3 Surface SEM images for the annealed films grown on sapphire with the different ratios of Ca/Co: (a) 1 : 1.38; (b) 1 : 0.82; (c) 1 : 0.67; (d) 1 : 0.52.



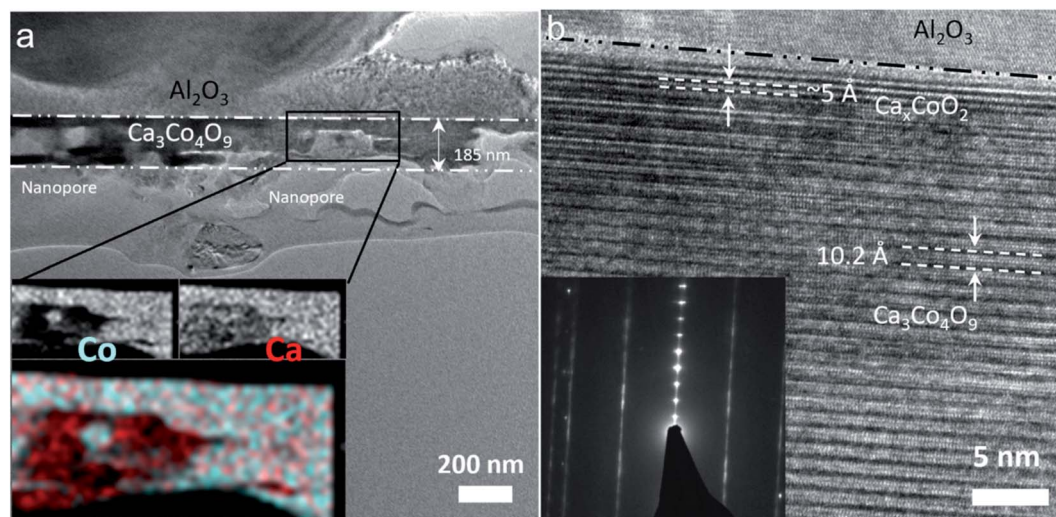


Fig. 4 The cross-sectional TEM images of the annealed film with the ratio of Ca/Co = 1 : 0.82 deposited on sapphire: (a) low-magnification TEM image and the inset of EDS spectral maps of Ca and Co for nanopores, and (b) the corresponding high-resolution TEM images and inset of the SAED patterns capturing the layered atomic structure of $\text{Ca}_3\text{Co}_4\text{O}_9$.

of grains (Fig. 3c). The similar round grains with a “size” (~ 100 nm) can be observed on the top of the flat grains and nanopores at films 1 : 0.82 and 1 : 0.6 in Fig. 3b and c. For the lowest Co containing film, different family of grains can be observed forming a dense film (without apparent nanopores) (Fig. 3d).

The cross-sectional TEM images of the annealed film with the ratio of Ca : Co = 1 : 0.82 deposited on sapphire are shown in Fig. 4a and b. The nanopore structure in the $\text{Ca}_3\text{Co}_4\text{O}_9$ layer with an apparent thickness of 185 nm can be observed in Fig. 4a, with the EDS maps of Co and Ca elements showing a uniform distribution in the $\text{Ca}_3\text{Co}_4\text{O}_9$ layer but a higher Ca concentration in the nanopores. At the interface film substrate, a thin Ca_xCoO_2 layer can be seen near the sapphire substrate in Fig. 4b. The formation of Ca_xCoO_2 has been observed in earlier work.²² The lattice images for the $\text{Ca}_3\text{Co}_4\text{O}_9$ layer and the SAED patterns (Fig. 4b) confirm that the (001) basal planes are oriented parallel to the film surface, corroborating the XRD results.

The dense $\text{Ca}_3\text{Co}_4\text{O}_9$ film can be synthesized with the right Ca : Co elemental ratio (close to stoichiometric $\text{Ca}_3\text{Co}_4\text{O}_9$) when the film grows on sapphire. The nanoporous film but a non-phase pure film mixing CaO and $\text{Ca}_3\text{Co}_4\text{O}_9$ can form on sapphire with increasing Ca content. Comparing the results for the films grown on sapphire with those on mica allows

determining the mechanism of the increase in the porosity fraction and formation of a discontinuous film of islands, effectively constituting distributed nanoparticles.

This discontinuous structure is correlated with the reaction between Ca in the $\text{Ca}(\text{OH})_2/\text{Co}_3\text{O}_4$ multilayer films with the mica layer. In our previous work, pore formation could be attributed to the basal plane removal driven by local densification of textured $\text{Ca}_3\text{Co}_4\text{O}_9$ nuclei during growth.¹² In the present case, this mechanism yields formation of a discontinuous film of islands, *i.e.*, distributed nanoparticles, for the high initial Ca content in the starting multilayers. A schematic illustration is shown in Fig. 5. When Ca : Co = 1 : 1.38 (close to 3 : 4), the film with few nanopores is composed of a crystalline $\text{Ca}_3\text{Co}_4\text{O}_9/\text{Co}_3\text{O}_4$ layer on top of a thin amorphous layer, which proves that Ca diffuses and reacts with the mica substrate to form an amorphous layer during formation of $\text{Ca}_3\text{Co}_4\text{O}_9$. During annealing and with increased Ca content, the excess Ca from $\text{Ca}(\text{OH})_2$ will be attracted to the interface substrate/film where the reaction occurs to form a thicker amorphous layer underneath phase pure crystalline $\text{Ca}_3\text{Co}_4\text{O}_9$ layers with nanopores. With further increase of Ca content, the nanopore size and porosity significantly increase, while the apparent thickness of the crystalline $\text{Ca}_3\text{Co}_4\text{O}_9$ layer remains constant. This result indicates that the volume shrinkage of $\text{Ca}_3\text{Co}_4\text{O}_9$

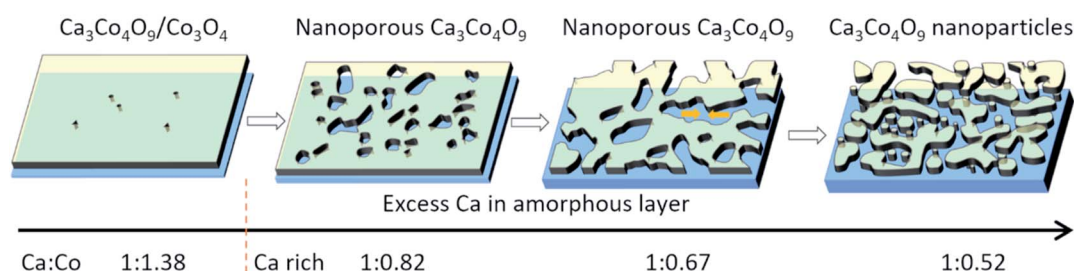


Fig. 5 Schematic illustration of formation of $\text{Ca}_3\text{Co}_4\text{O}_9$ nanoparticles.

preferentially occurs in the in-plane direction and not in the out-of-plane direction. As expected, the more excess Ca results in a thicker amorphous layer with even lower Co content. Instead of forming nanoporous $\text{Ca}_3\text{Co}_4\text{O}_9$, the $\text{Ca}_3\text{Co}_4\text{O}_9$ instead forms a discontinuous film of islands, constituting distributed nanoparticles with a larger apparent “porosity”.

The growth of discontinuous films with islands of highly textured $\text{Ca}_3\text{Co}_4\text{O}_9$ effectively constituting distributed nanoparticles has been demonstrated by sequential sputtering-annealing without any templates. The volume shrinkage in the initial $\text{Ca}(\text{OH})_2/\text{Co}_3\text{O}_4$ multilayers with different Ca/Co overall ratios can be used to tailor morphology and surface coverage porosity in textured $\text{Ca}_3\text{Co}_4\text{O}_9$ films. Such films of discontinuously dispersed $\text{Ca}_3\text{Co}_4\text{O}_9$ nanoparticles may be a promising filler in polymer matrixes for hybrid and composite materials in, e.g., hybrid thermoelectrics.

Conflicts of interest

There are no conflicts to declare.

Notes and references

- 1 Y. Miyazaki, M. Onoda, T. Oku, M. Kikuchi, Y. Ishii, Y. Ono, Y. Morii and T. Kajitani, *J. Phys. Soc. Jpn.*, 2002, **71**, 491–497.
- 2 D. W. Kim, Y. D. Ko, J. G. Park and B. K. Kim, *Angew. Chem., Int. Ed.*, 2007, **46**, 6654–6657.
- 3 S. Guan, Q. Fan, L. Liu, J. Luo, Y. Zhong, W. Zhao, Z. Huang and Z. Shi, *Sci. China: Technol. Sci.*, 2020, **64**, 673–679.
- 4 C. S. Lim, C. K. Chua, Z. Sofer, O. Jankovský and M. Pumera, *Chem. Mater.*, 2014, **26**, 4130–4136.
- 5 V. D. Silva, T. A. Simões, F. J. A. Loureiro, D. P. Fagg, E. S. Medeiros and D. A. Macedo, *Mater. Lett.*, 2018, **221**, 81–84.
- 6 Z. Wang, Y. Wang, X. Yue, G. Shi, M. Shang, Y. Zhang, Z. Lv and G. Ao, *J. Alloys Compd.*, 2019, **792**, 357–364.
- 7 R. Mendoza, J. Oliva, K. P. Padmasree, A. I. Oliva, A. I. Mtz-Enriquez and A. Zakhidov, *J. Energy Storage*, 2022, **46**, 103818.
- 8 J. Snyder, I. McCue, K. Livi and J. Erlebacher, *J. Am. Chem. Soc.*, 2012, **134**, 8633–8645.
- 9 D.-J. Guo and Y. Ding, *Electroanalysis*, 2012, **24**, 2035–2043.
- 10 J. Tang, H. T. Wang, D. H. Lee, M. Fardy, Z. Huo, T. P. Russell and P. Yang, *Nano Lett.*, 2010, **10**, 4279–4283.
- 11 B. Paul, Y. Zhang, W. Zhu, B. Xin, G. Ramanath, T. Borca-Tasciuc and P. Eklund, *Appl. Phys. Lett.*, 2022, **120**, 061904.
- 12 B. Xin, A. L. Febvrier, R. Shu, A. Elsukova, V. Venkataramani, Y. Shi, G. Ramanath, B. Paul and P. Eklund, *ACS Appl. Nano Mater.*, 2021, **4**, 9904–9911.
- 13 Y. Du, J. Xu, B. Paul and P. Eklund, *Appl. Mater. Today*, 2018, **12**, 366–388.
- 14 Y. Wang, L. Yang, X. L. Shi, X. Shi, L. Chen, M. S. Dargusch, J. Zou and Z. G. Chen, *Adv. Mater.*, 2019, **31**, e1807916.
- 15 L. Zhang, X.-L. Shi, Y.-L. Yang and Z.-G. Chen, *Mater. Today*, 2021, **46**, 62–108.
- 16 L. Wang, Z. Zhang, Y. Liu, B. Wang, L. Fang, J. Qiu, K. Zhang and S. Wang, *Nat. Commun.*, 2018, **9**, 3817.
- 17 B. Xin, A. L. Febvrier, L. Wang, N. Solin, B. Paul and P. Eklund, *Mater. Des.*, 2021, **210**, 110033.
- 18 M. D. Abràmoff, P. J. Magalhães and S. J. Ram, *Biophot. Int.*, 2004, **11**, 36–42.
- 19 B. Paul, J. Lu and P. Eklund, *ACS Appl. Mater. Interfaces*, 2017, **9**, 25308–25316.
- 20 B. Paul, E. M. Björk, A. Kumar, J. Lu and P. Eklund, *ACS Appl. Energy Mater.*, 2018, **1**, 2261–2268.
- 21 B. Xin, E. Ekström, Y.-T. Shih, L. Huang, J. Lu, A. Elsukova, Y. Zhang, W. Zhu, T. Borca-Tasciuc, G. Ramanath, A. Le Febvrier, B. Paul and P. Eklund, *Nanoscale Adv.*, 2022, DOI: [10.1039/D2NA00278G](https://doi.org/10.1039/D2NA00278G).
- 22 B. Paul, J. L. Schroeder, S. Kerdsonpanya, N. V. Nong, N. Schell, D. Ostach, J. Lu, J. Birch and P. Eklund, *Adv. Electron. Mater.*, 2015, **1**, 1400022.

